



# 2SB1165/2SD1722

## 50V/5A Switching Applications

### Applications

- Relay drivers, high-speed inverters, converters.

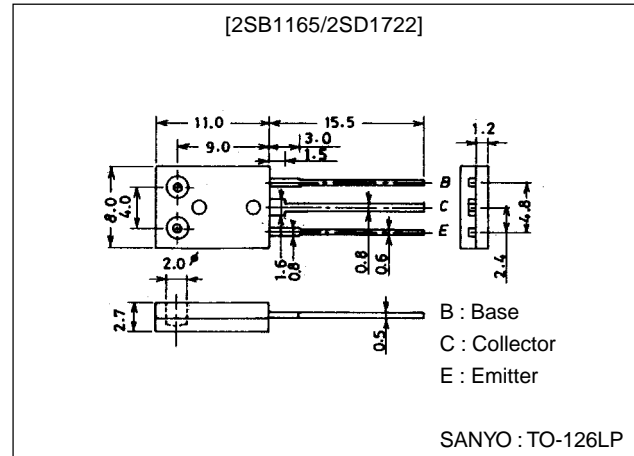
### Features

- Low collector-to-emitter saturation voltage.
- High  $f_T$ .
- Excellent linearity of  $h_{FE}$ .
- Fast switching time.

### Package Dimensions

unit:mm

2043A



() : 2SB1165

### Specifications

#### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CB0}$		(-)60	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-)50	V
Emitter-to-Base Voltage	$V_{EBO}$		(-)6	V
Collector Current	$I_C$		(-)5	A
Collector Current (Pulse)	$I_{CP}$		(-)8	A
Collector Dissipation	$P_C$		1.2	W
		$T_c=25^\circ\text{C}$	20	W
Junction Temperature	$T_j$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

#### Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=-40\text{V}, I_E=0$			(-)1	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=-4\text{V}, I_C=0$			(-)1	$\mu\text{A}$
DC Current Gain	$h_{FE1}$	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$	70*		400*	
	$h_{FE2}$	$V_{CE}=-2\text{V}, I_C=-4\text{A}$	35			
Gain-Bandwidth Product	$f_T$	$V_{CE}=-5\text{V}, I_C=-1\text{A}$		180		MHz
				(130)		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=-10\text{V}, f=1\text{MHz}$		40(60)		pF

\* : The 2SB1165/2SD1722 are classified by 0.5A  $h_{FE}$  as follows :

70	Q	140	100	R	200	140	S	280	200	T	400
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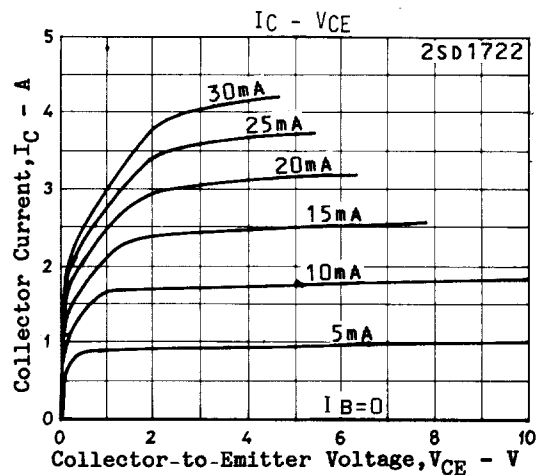
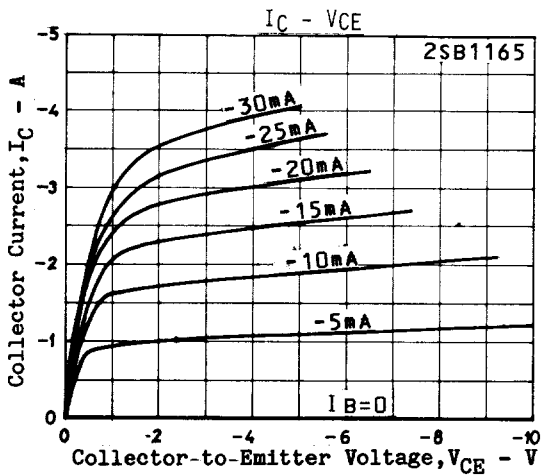
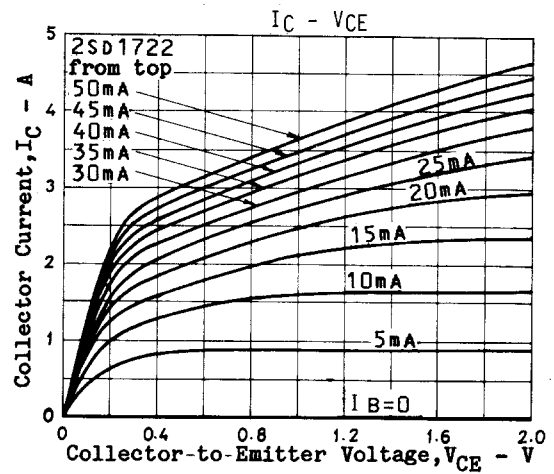
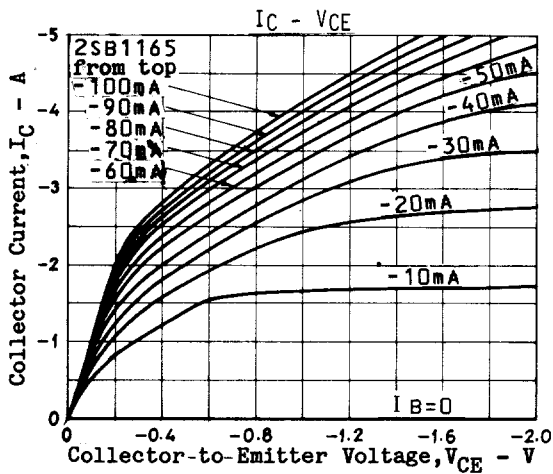
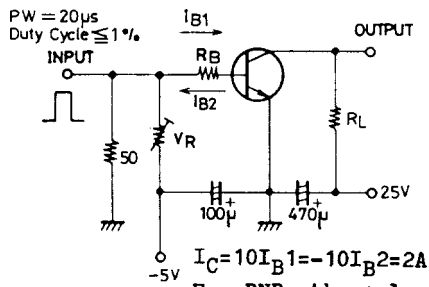
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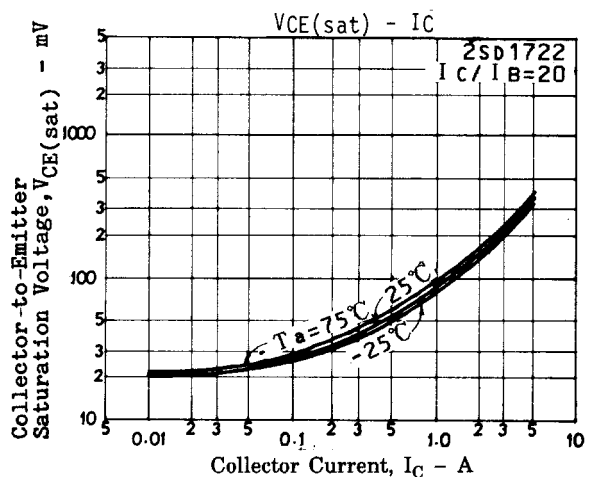
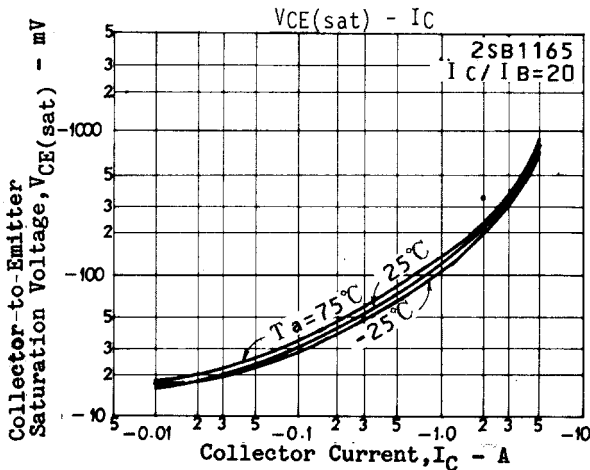
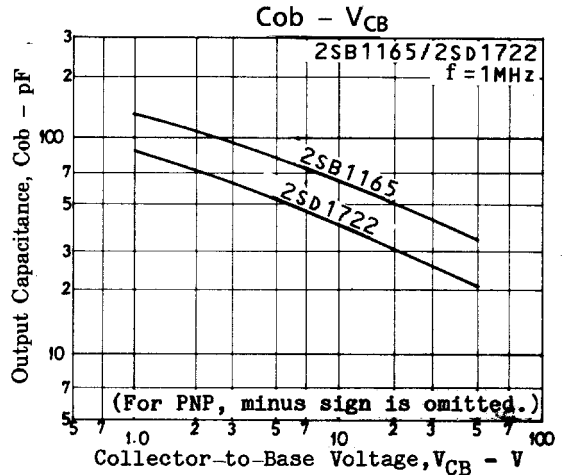
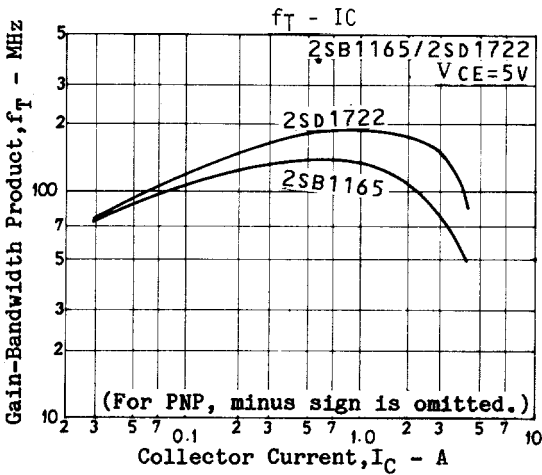
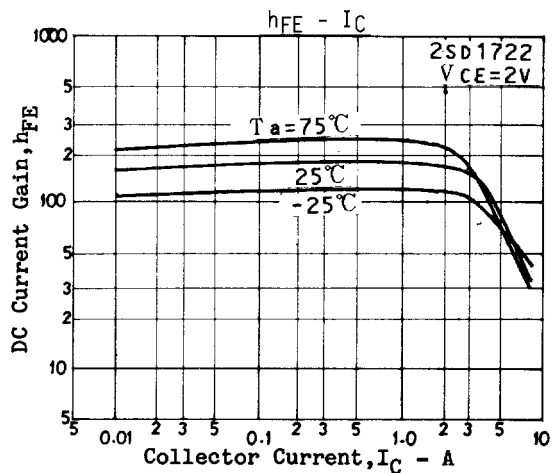
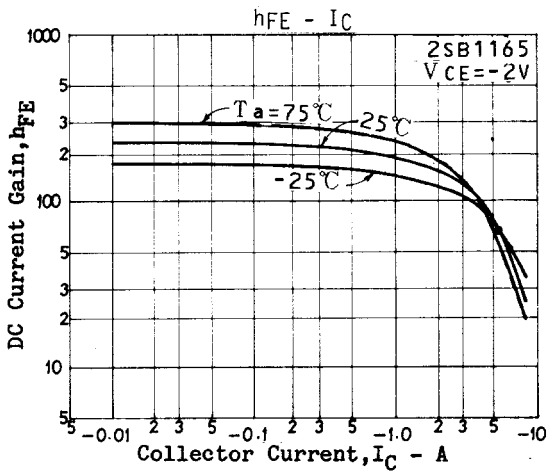
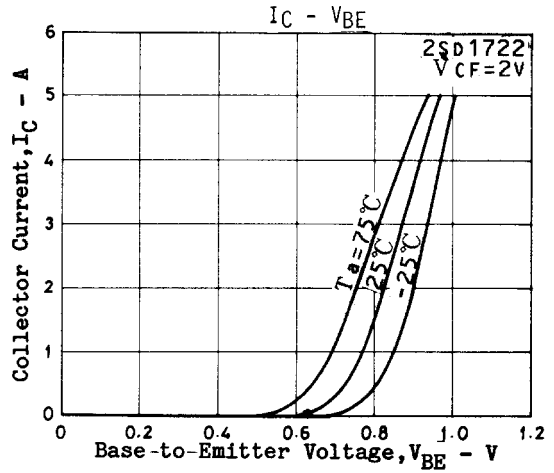
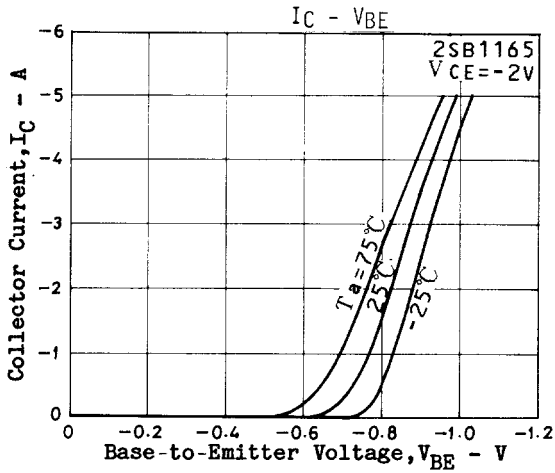
# 2SB1165/2SD1722

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)3A, I_B=(-)0.15A$		220	400	mV
				(-280)	(-550)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)3A, I_B=(-)0.15A$		(-)0.95	(-)1.3	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)6			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		(50)50		ns
Storage Time	$t_{stg}$	See specified Test Circuit		500		ns
				(450)		ns
Fall Time	$t_f$	See specified Test Circuit		20(20)		ns

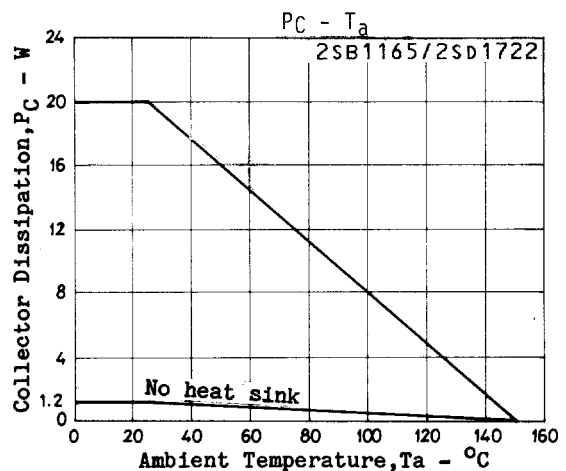
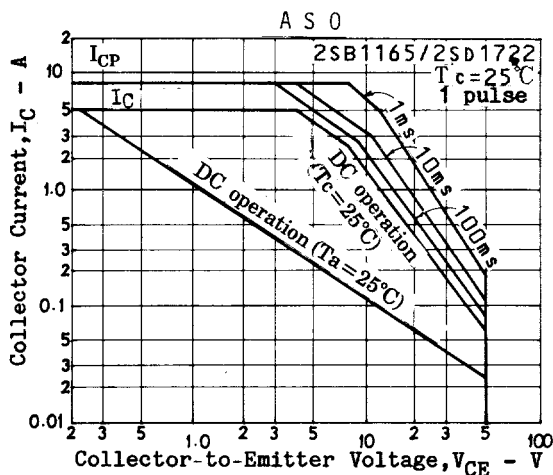
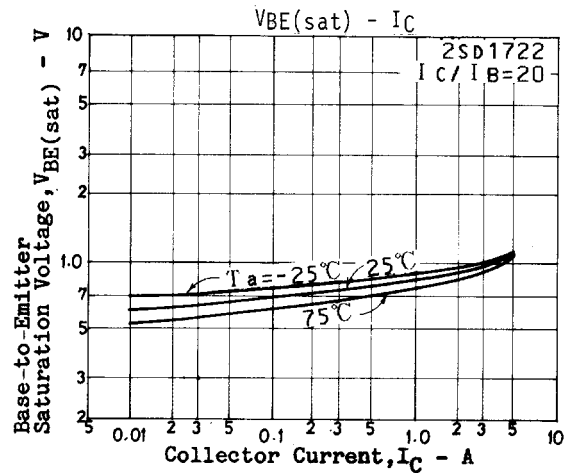
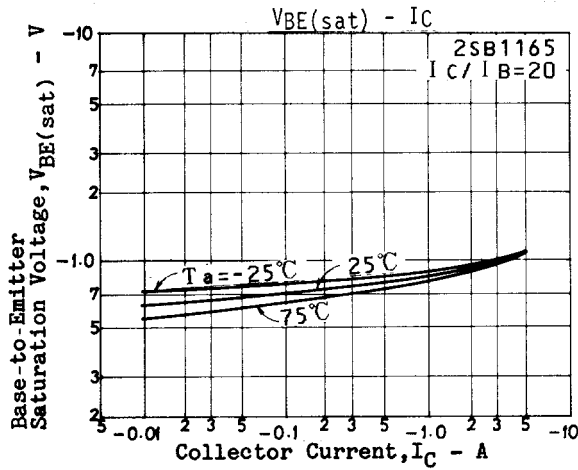
## Switching Time Test Circuit



# 2SB1165/2SD1722



## 2SB1165/2SD1722



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